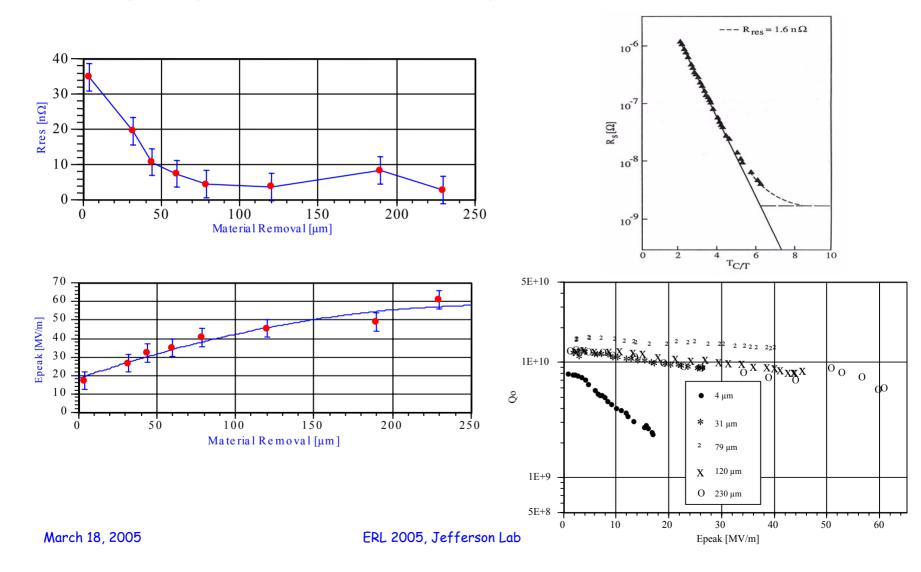
Cavity Preparation/Assembly Techniques and Impact on Q Realistic Q-factors in a Module, Review of Modules

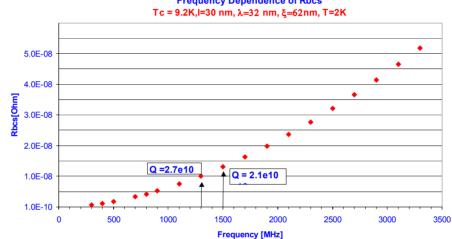
> P. Kneisel Jefferson Lab

Why Surface Treatment? Damage layer influences cavity Performance



What is the goal of the surface treatment?

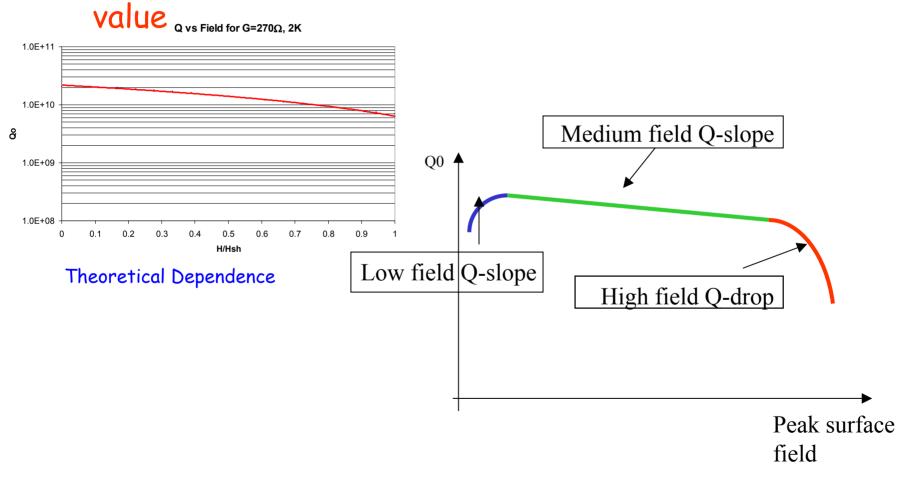
Get as close as possible to an ideal surface, achieve fundamental limits of the material: very low R_{res} , $H_{crit} \sim 185 \text{ mT}$



- Remove the surface damage layer (> 100 μ m)
- Defect-free surface
- Contamination-free to avoid FE
- Smooth for better cleaning, avoid field enhancements...

Obstacles

Even if the low field Q is high (residual resistance low), there is typically a field dependence of the Q-



Q vs E_{acc}, "Q-drop"

- For high RRR niobium often a degradation of the Q value is observed at gradients (magnetic surface fields) above ~ 20 MV/m (>90 mT)
- "In situ" baking of the cavities at 120C for long periods of time (~48 hrs) improves the Q-values at lower power and in the Q-drop regime
- The improvement is often more pronounced for EP cavities, but is also observed for BCP'd cavities
- The physics of the Q-drop is still not understood explanations range from field enhancements at grain boundaries to effects in the metal-oxide interface or weak links at grain boundaries
- It is clear that oxygen diffusion from the surface into the material plays a role; the depth of the affected zone is several hundred nm

Q vs E_{acc}, "Q-drop"

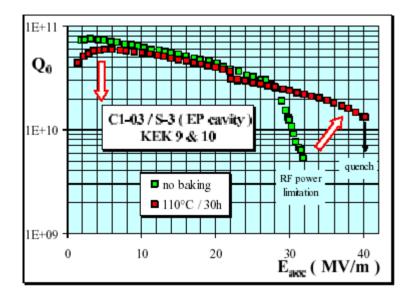


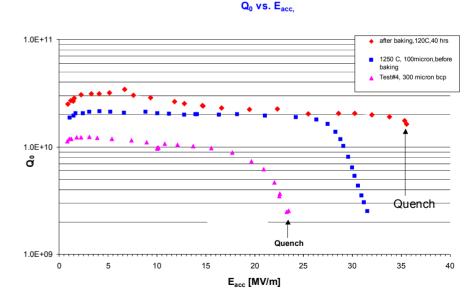
Figure 4: Baking effect on C1-03 Saclay cavity (electropolished and tested at KEK) [9].

[B.Visentin, SRF2003]

electropilished

Buffered Chemical Polished(1:1:1)

CEBAF Single cell cavity Nb/Ta 1162_33/1162_34

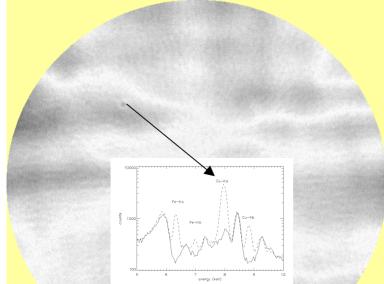


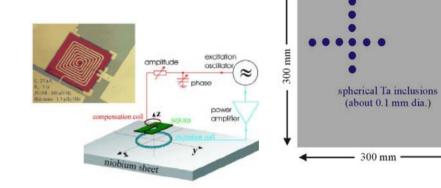
Surface Treatment Procedures

- Eddy CurrentScanning, Squid Scanning (successfully used at DESY on TTF cavities)
- Degreasing (ultrasound + soap+water, solvents)
- BCP (HF:HNO₃:H₃PO₄ as 1:1:1, 1:1:2,1:1:4) (room temperature or below to avoid excessive hydrogen pick-up)
- Electropolishing (HF/H₂SO₄ Siemens-KEK-Recipes)
- Barrel Polishing
- High pressure Ultrapure Water Rinsing
- High Temperature Heat Treatment (600C to 1400C for Hydrogen degassing, Post Purification)
- "In-situ" baking (typically 120C for> 24 hrs)
- Alternative Cleaning: CO₂ Snow, Megasonic, UV Ozon..

Scanning of Niobium Sheets Successfully developed at DESY to pre-screen Nb Sheets for defects: eddy current, resolution ~ 100 µm squid, resolution < 50 µm







Low Tc superconducting SQUID system for eddy current testina of niobium sheets is in developn

(W.Singer, X.Singer)

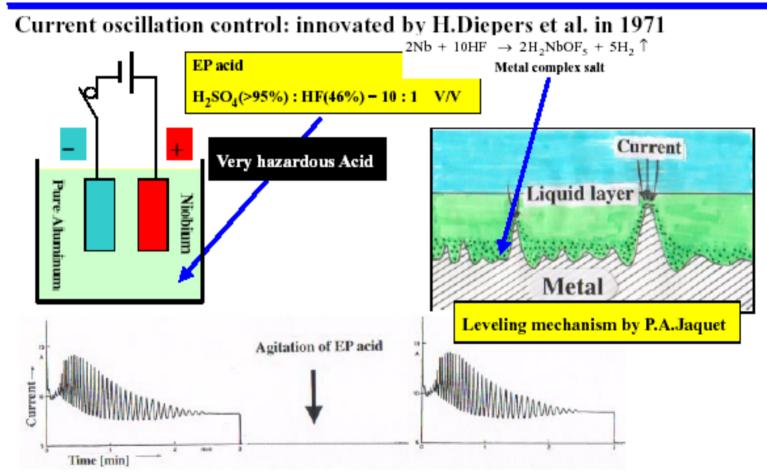
5. Jefferson Lab

-dimensional distribution of eddy-current field above the niobaum test sample, measured from the sake side of the sample. The excitation coil had 30 turns and a diamter of 3 mm, the excitation

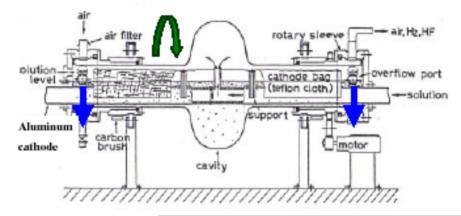
Two-dimensional distribution of eddy-current field above the niobium test sample, measured from the back side of the sample. The excitation coil thad 30 turns and a diamter of 37 mm, the excitation frequency was 10 kHz. The reference phase of the lock-in amplifier was chosen such that the lift-off effect was minimized.

Talk by K.Saito in JLAB on Oct. 2003

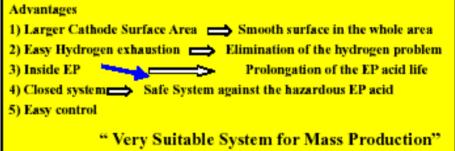
Electropolishing of Niobium



Talk by K.Saito in JLAB on Oct. 2003 Horizontally Rotated Continuous EP (HRC-EP)







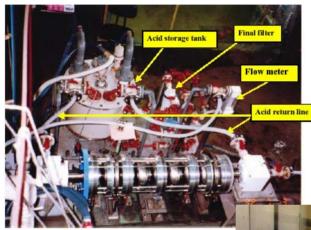
Electropolishing, cont'd

Activities

Lab	What has been done/is being done?	Reference
KEK/ Nomura Plating	Developed EP based on Siemens Recipe Successfully applied to Tristan & B- factory cavities Developed Hydrogen -free EP: HNO ₃ add	K.Saito(1991) T.Higuchi,K.Saito (2003)
DESY/ TTF	Implemented,commissioned and uses system for multi-cell EP CARE: optimizing parameter (Saclay) industrializing/automating (INFN)	CARE 2004- Meeting
Jlab	Implemented and commissioned system in 2003/2004, starting to develop parameters	
Cornell March 18, 2005	Vertical system for single cells ERL 2005, Jefferson Lab	R.Geng(2004)

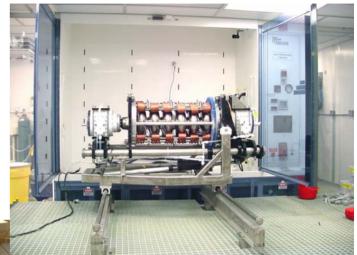
EP-Systems

KEK/Nomura Plating



DESY

JLab

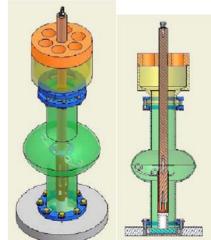


INFN



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Cornell



March 18, 2005

High Pressure Water Rinsing

- Universally used as last step in surface preparation
- Water: ultrapure, resistivity > 18 M Ω cm
- Pressure: ~ 100 bar (1200 psi)
- Nozzle configuration: varying, SS or sapphire
- "Scanning": single or multiple sweeps,

continuous rotation + up/down

• Add. HPR after attachment of auxiliary components

High Pressure Rinse Systems



DESY-System



March 18, 2005



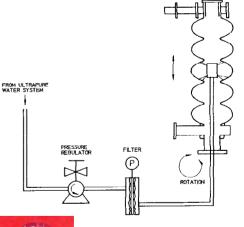
Jlab HPR Cabinet



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KEK-System



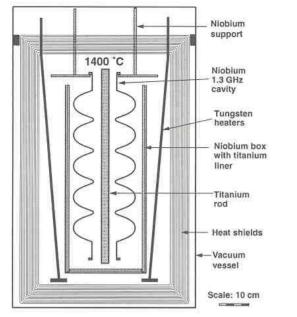


High Temperature Heat Treatment UHV Heat Treatment of Niobium used since the "beginning of times"; nowadays :

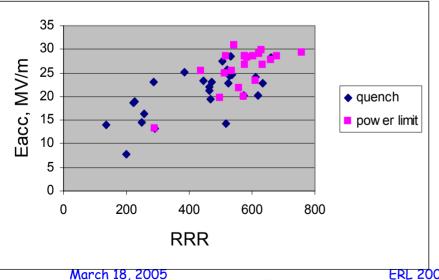
- Hydrogen degassing: 600C for 10 hrs at Jlab
- Annealing:
- Post- Purification:

750 C for 3 hrs at KEK 800 C, several hrs

1200C to 1400C in presence of a solid state getter, e.g.Ti Improvement of RRR Loss of mechanical properties grain growth

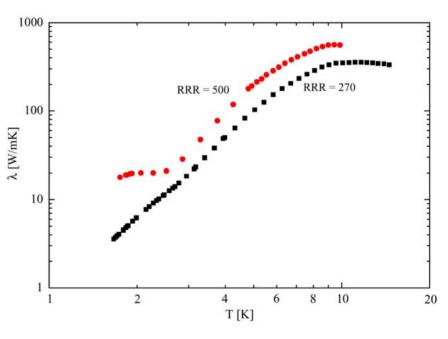


Cavity post purification (solid state gettering)



Post purification of Nb [W.Singer, 2003]

Thermal conductivity of samples from the niobium sheets used in the TESLA cavities: before and after the 1400 °C heat treatment (RRR = 270 and RRR = 500 respectively)



The heat treatment also homogenize the Nb (reduction of magnetic flux pinning centers shown by

ERL 2005, Jefferson Lab magnetization measurement)

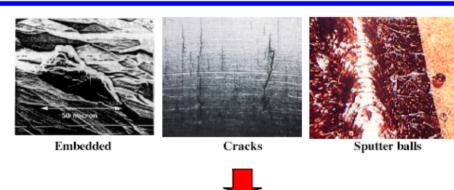
Eacc versus RRR of TTF cavities

Centrifugal Barrel Polishing(CBP)(1)

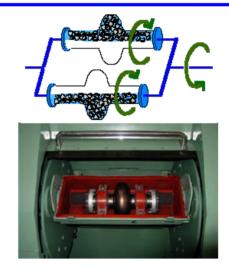
- Barrel Polishing ("tumbling") developed at KEK for smoothening of surfaces/welds
 plastic stones, water + abrasive
- Process very slow, by adding motion, removal rate increased 10fold: ~ 44 mm in 8 hrs
- During the process, hydrogen is dissolved in the niobium("Q-disease") and needs to be removed by furnace treatment
- Hydrogen-free CBP accomplished by using a different (hydrogen-free) agent:FC-77 (C8F18,C8F16 O) [T.Higuchi,K. Saito SRF 2003]

Centrifugal Barrel Polishing(2)

Purpose of mechanical grinding



Mechanical grinding is a powerful method to remove surface defects Centrifugal Barrel Polishing (CBP)



[T.Higuchi, K. Saito, SRF 2003]

CO₂ Snow Cleaning

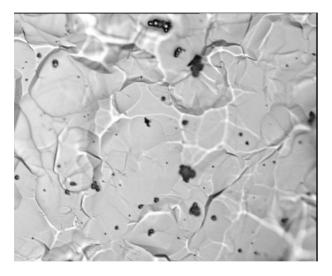
Developed at DESY (D.Reschke) as an alternative to HPR or "in situ" cleaning for modules

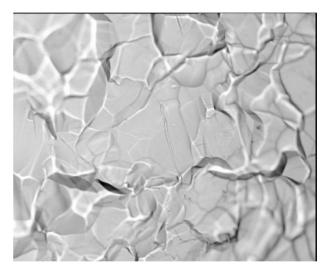
- A prototpye system has been fabricated and initial tests have been made on samples and on single cell cavities
- optimization of process necessary (cleaning effect; avoidance of condensation, mass flow)
- A production system is under construction and will be completed some time in the autumn of 2005

Preliminary Tests

- successful cleaning of Nb samples

=> investigation of field emission properties + reduction of particles collaboration with G. Müller, University of Wuppertal, Germany; see SRF Workshop 2001





Optical microscope images before (left) and after (right) dry-ice cleaning of an sample intentionally contaminated with Fe and Cu particles (500x mag)

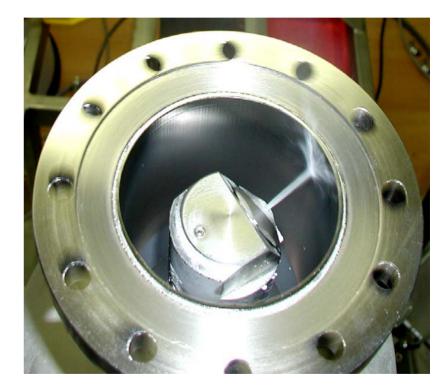
[L.Lilje, CARE Meeting Nov. 2004, DESY]

Cavity Tests on Mono-cells

 dedicated nozzle system for cavity cleaning developed [L.Lilje, CARE Meeting Nov. 2004, DESY]





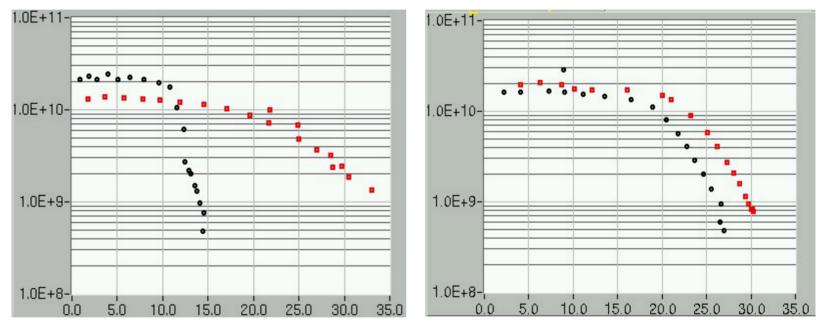


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First Results of Cavity Tests

- Q-values up to $4,0 \cdot 10^{10}$ at $1.8 \text{ K} \implies$ no surface contamination
- gradients up to 33 MV/m = field emission is limiting effect

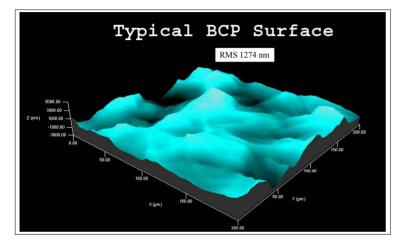


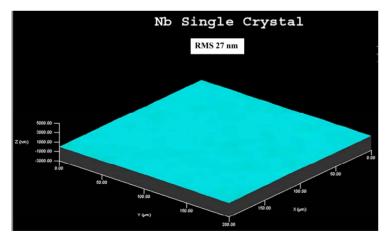
Q(E)-performance of two monocells before (black) and after (red) dry-ice cleaning

[L.Lilje, CARE Meeting Nov. 2004, DESY]

Single Crystal BCP

Provides very smooth surfaces as measured by A.Wu, Jlab





RMS: 1274 nm fine grain bcp 27 nm single crystal bcp 251 nm fine grain ep



Procedures: general remarks

- "Enemies" of good cavity performance are: insufficient material removal, defects and contamination (field emission)
- All procedures need to deal with these problems and the most difficult is control of contamination
- Level of contamination is different in different labs and depends on facilities, design, auxiliary parts, hardware (e.g. bolts, gaskets..) and people
- Optimum procedures have to be developed for each lab and project

"Standard" Treatment Procedures(1)

BCP, TTF Module 1-5, SNS

- Outside bcp(> 20 μ m), inside bcp (80-100 μ m), clean water rinsing
- Hydrogen degassing (600C-SNS, 800C TTF)
- Rinsing in UPW, post-purification with Ti, 1400C
- + BCP to remove Ti surface layer: 80 μm inside, 40 μm outside, UPW rinse
- Re-tuning

20 µm inside bcp, UHP water rinse HPR, drying in class 10, open, 12 hrs Assembly of auxiliary parts Vacuum leak check of flange connections Venting, dismount pumping flange 1. + 2. HPR(check of particle#, TOC...) Installation of antenna for VTA test

No VTA test of bare cavity for SNS

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"Standard" Treatment Procedures(2)

- Helium vessel welding with inert gas inside cavity(TIG or EBW)
- Preparation for

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Horizontal test (Chechia) Inside bcp 20 µm, HPR Drying in class 10 Assembly of auxiliary parts Leak check 1. + 2. HPR, drying in class 10 Assembly of final flange Evacuating, leak check, venting Assembly of power coupler (avoids losing conditioning effect) Horizontal test

Vertical test

50 µm bcp, UPW rinsing
2 passes HPR, drying in class10,12 hrs
Assembly of auxiliary parts
2 passes HPR, drying in class 10
Final flange/pump-out port assembly
Evacuation, leak check
Hermetically sealed on test stand
Test at 2K

"Standard" Treatment Procedures(3)

After qualification of cavity with He-vessel

- Cleaning for string assembly
- ("dirty" → class 10000⇒ class 10)
- Venting of cavity in class 10
- Assembly of gate valves, magnets..
- "on the job" cleaning of bolted beam pipe flanges necessary
- Final leak check
- Venting for transportation to installation in cryostat
- assembly

- After VTA Test(without HOM probes and FPC):
- •Add. 10 –20 μm bcp, HPR for 4 hrs, drying in class 10 clean room over night
- Attachment of HOM probes
- •Add. 4 hrs of HPR, drying in class 10
- •Assembly on assembly rail with FPC, bellows, gate valves, beam pipe opening closed with Nb plate
- •Assembly of string takes several days
- •Final completion with beam pipe bellows,
- •Evacuation with turbo pump, leak checking

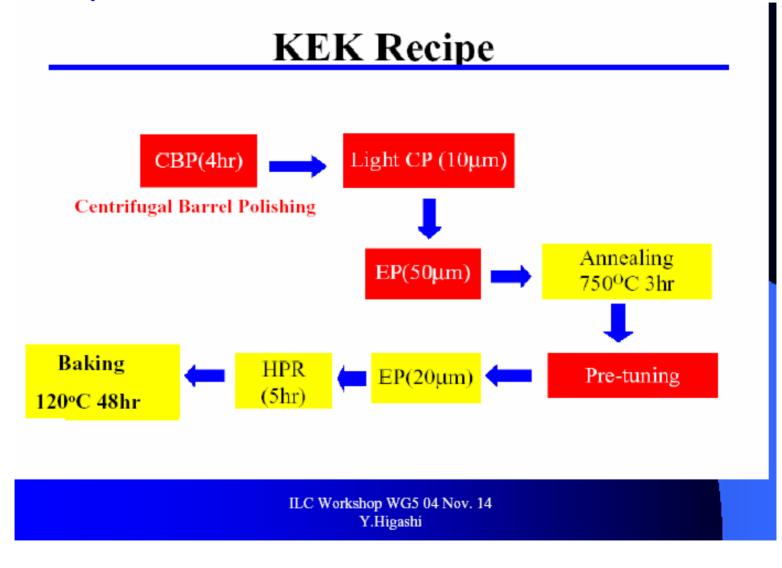
String Assembly



Modules SNS Medium Beta Cavity String

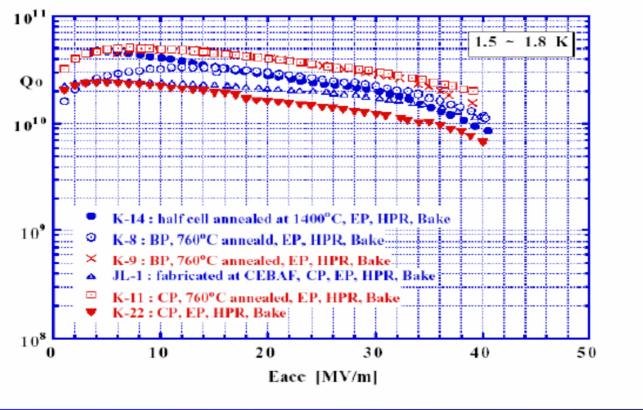






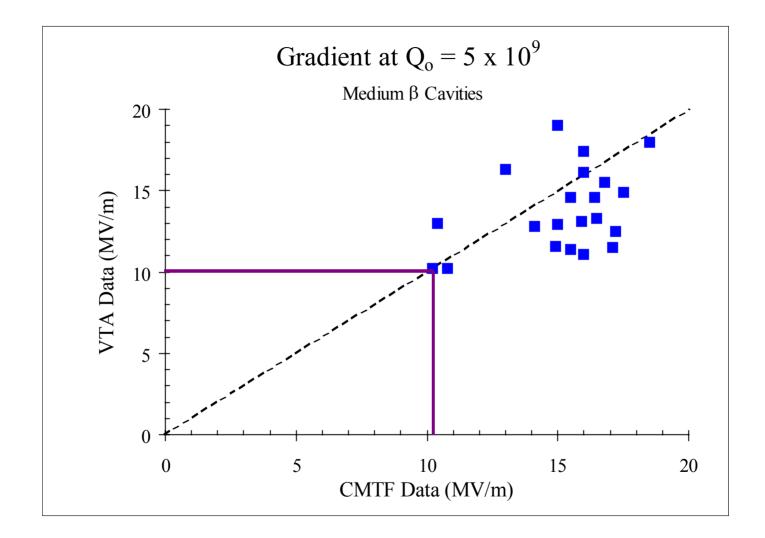
Recipes-KEK

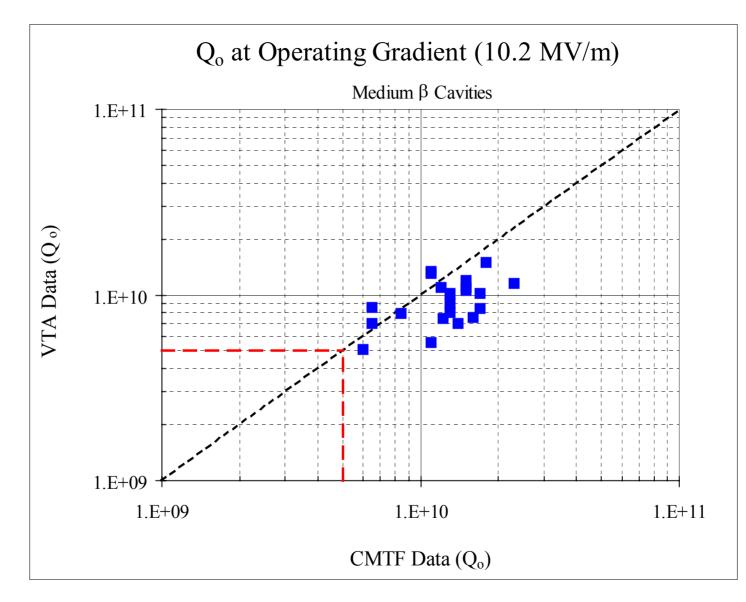
Single cell cavity performance by KEK recipe

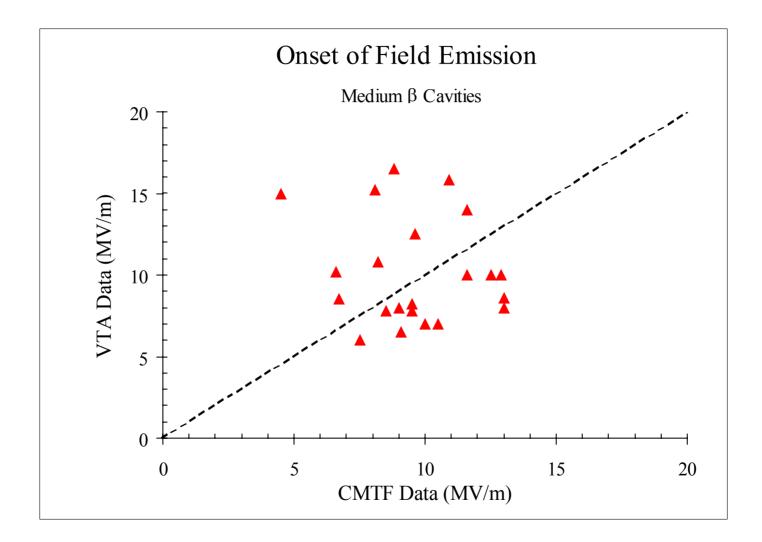


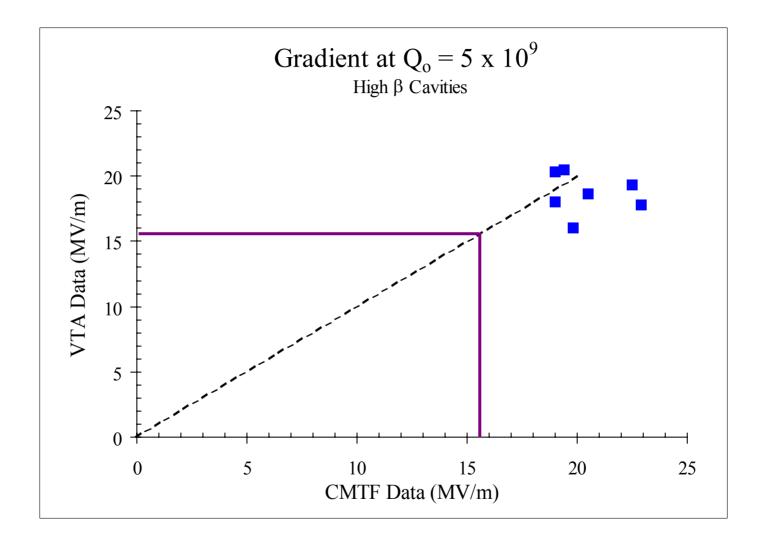
ILC Workshop WG5 04 Nov. 14 Y.Higashi

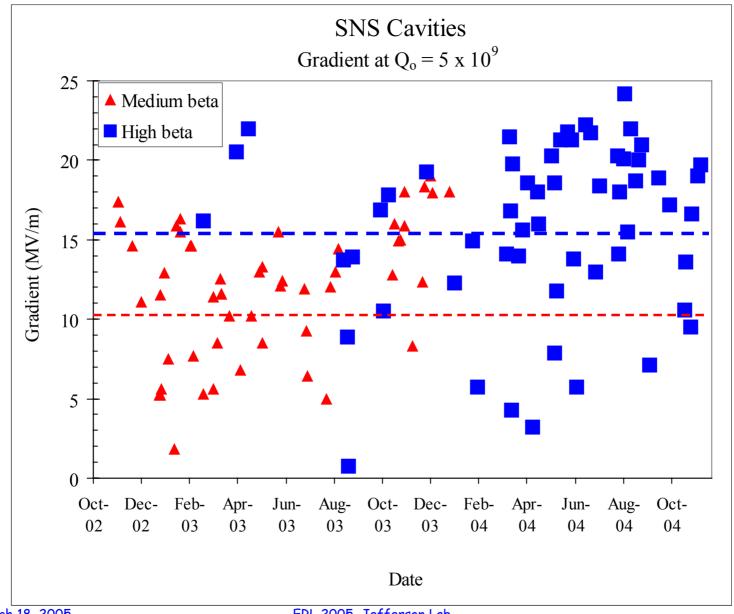
SNS- Modules



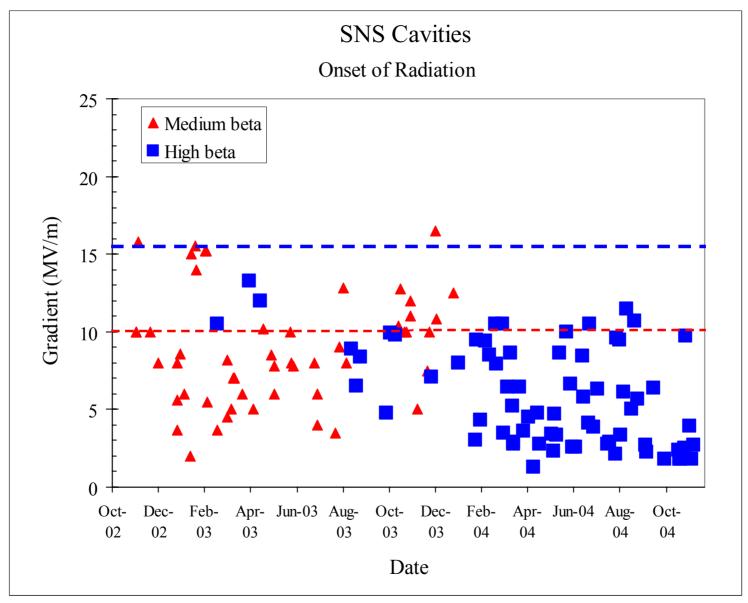


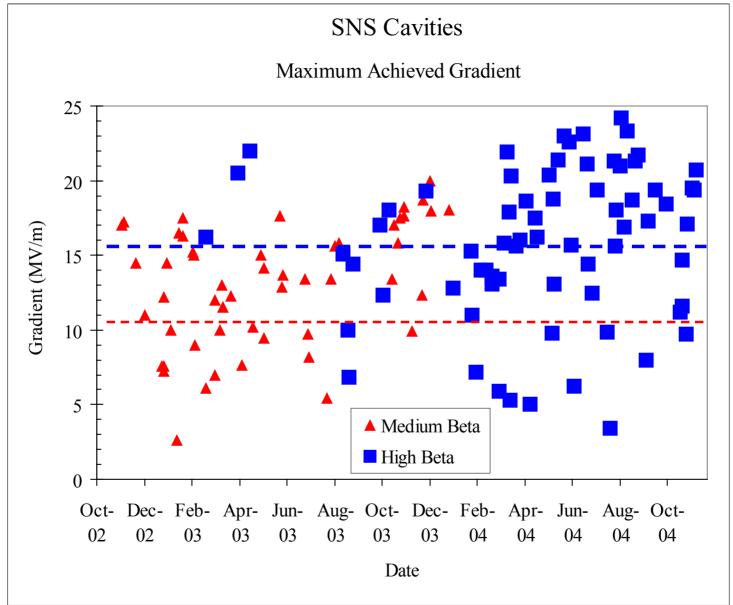


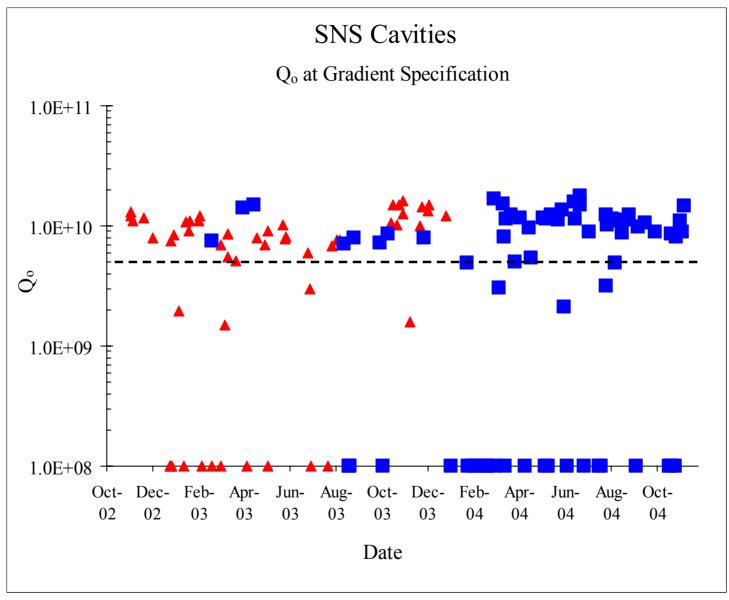




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The TTF Linac's Accelerating Cavities

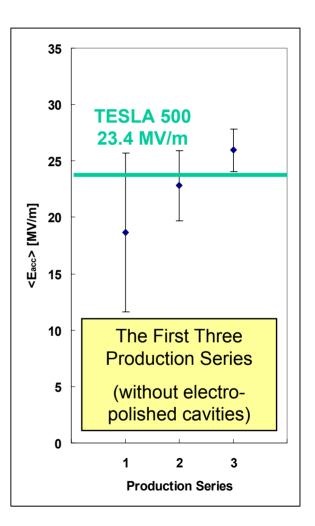


Approx. 80 cavities were produced in three production series. **Gradient and gradient spread improved a lot.**

Nine accelerator modules with 8 cavities each were assembled.

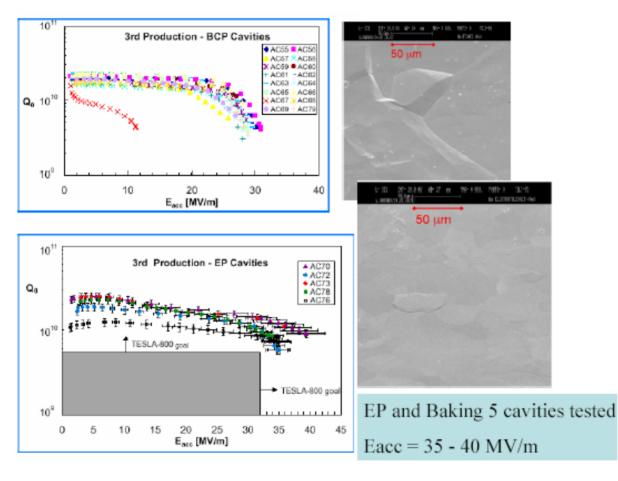
58 different cavities were used for the module assembly. Some cavities were used for a second assembly.

Series 1	18.7 ± 7.0
Series 2	22.8 ± 3.1
Series 3	26.0 ± 1.9

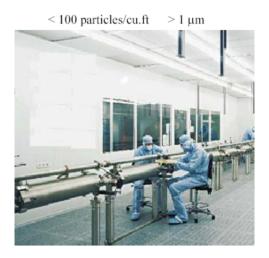


DESY/TTF

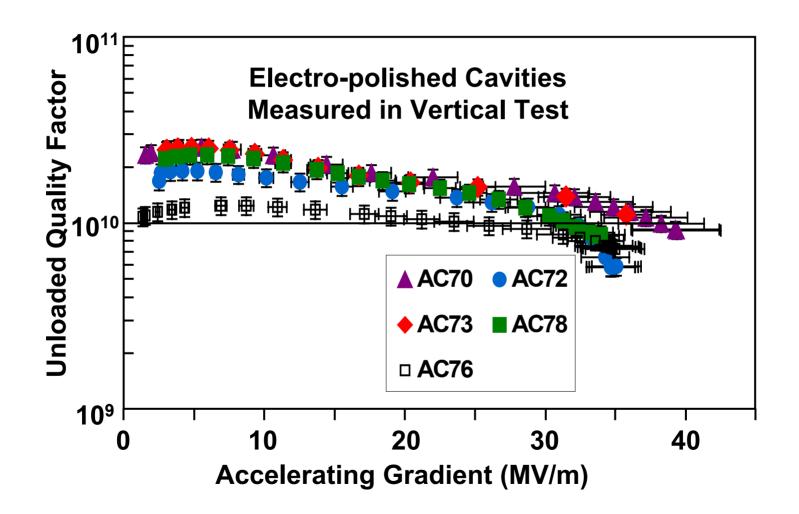
Vertical tests



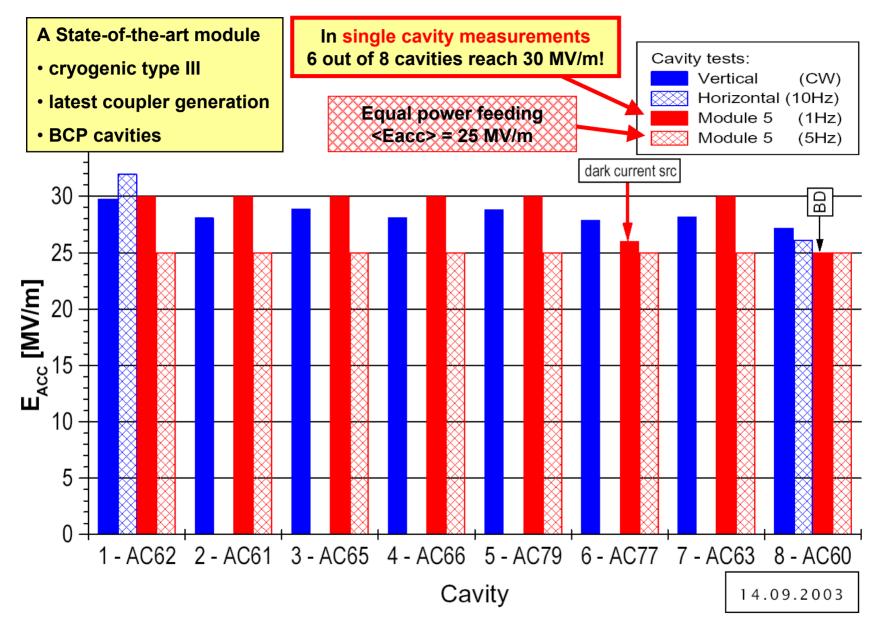
Assembly in Class 100 Clean Room



Electro-Polishing becomes State-of-the-Art Surface Preparation Technique and will be used for the XFEL



Performance of Accelerator Module 5



Dark Current Measurement

The on-axis dark current was measured for modules ACC4 / ACC5.

Only one cavity in module ACC5 produced a mentionable dark current.

- captured dark current could be measured at the exit of ACC5
- there was no d.c. from this cavity at the entrance of ACC4
- the d.c. decreased as a function of time

after module commissioning (August 2003) 100 nA at 16 MV/m increasing by a factor 10 for each 4.4 MV/m gradient step i.e. approx. 10 µA at 25 MV/m

May 4th

100 nA at 20 MV/m increasing by a factor 10 for each 3.7 MV/m gradient step, i.e. 1.2 µA at 25 MV/m

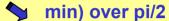
September 22nd

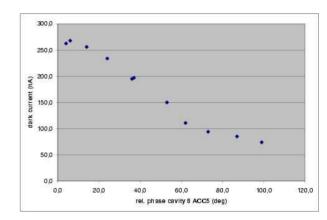
after a few weeks on-time at 20 - 25 MV/m 250 nA at 25 MV/m

 detuning of cavity no. 6 left over an integrated dark current of the order of 20 to 25 nA at 25 MV/m average gradient

Dark Current vs. RF phase with respect to neighbouring cavities is just as expected







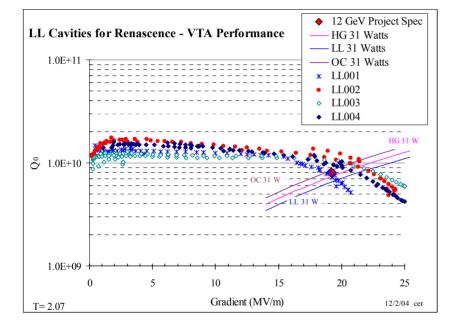
Reminder:

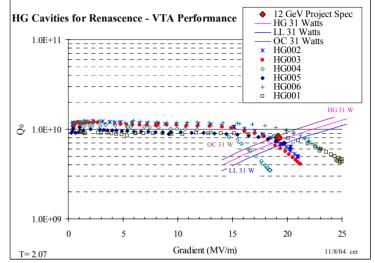
The TESLA limit is defined by additional cryogenic losses:

> The captured d.c. has to stay below 50 nA per cavity. (see TESLA Report 2003-10).

Jlab Upgrade: Renasence Module

5 LL cavities, 3 HG cavities







Acknowledgements

Many colleagues provided me with informations for this talk and I used slides from presentations by several colleagues:

C. Reece, Jlab, J. Ozelis, Jlab.H. Whitehead, Jlab A.Matheisen, DESY,L. Lilje, DESY,H. Weise, DESY, D. Reschke, DESY

http://adweb.desy.de/~weise/:Operational Experience with the TTF Linac

Das Europäische XFEL Projekt

http://www.aps.anl.gov/conferences/RFSC-Limits/Presentations.html D.Reschke,"Field Emission Overview ; Cleanliness and Processing" http://lcdev.kek.jp/ILCWS/WG5.php A.Matheisen,"Cavity fabrication and Processing" http://www-bd.fnal.gov/niobium/program.html W.Singer,"Material Properties of High Purity Niobium for SC Cavities"

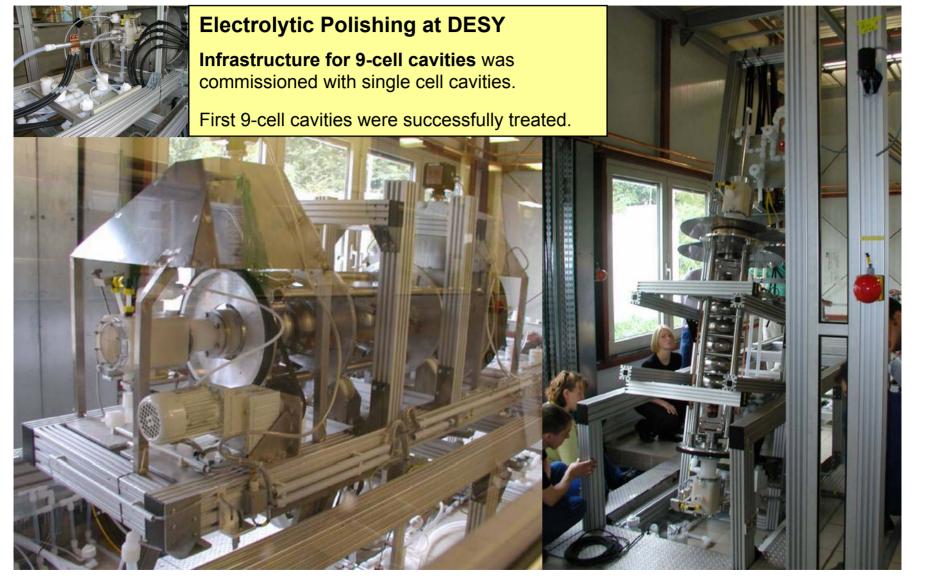
Back-up Slides

SNS: Cavity String Assembly

After VTA Test(without HOM probes and FPC):

- Add. 10 -20 μm bcp, HPR for 4 hrs, drying in class
 10 clean room over night
- Attachment of HOM probes
- Add. 4 hrs of HPR, drying in class 10
- Assembly on assembly rail with FPC, bellows, gate valves, beam pipe opening closed with Nb plate
- Assembly of string takes several days
- Final completion with beam pipe bellows,
- Evacuation with turbo pump, leak checking

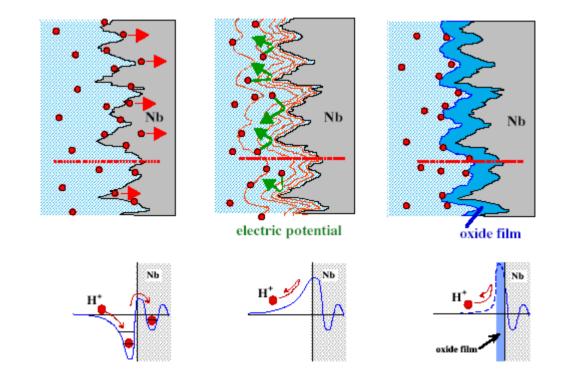
35 MV/m for 800 GeV c.m.



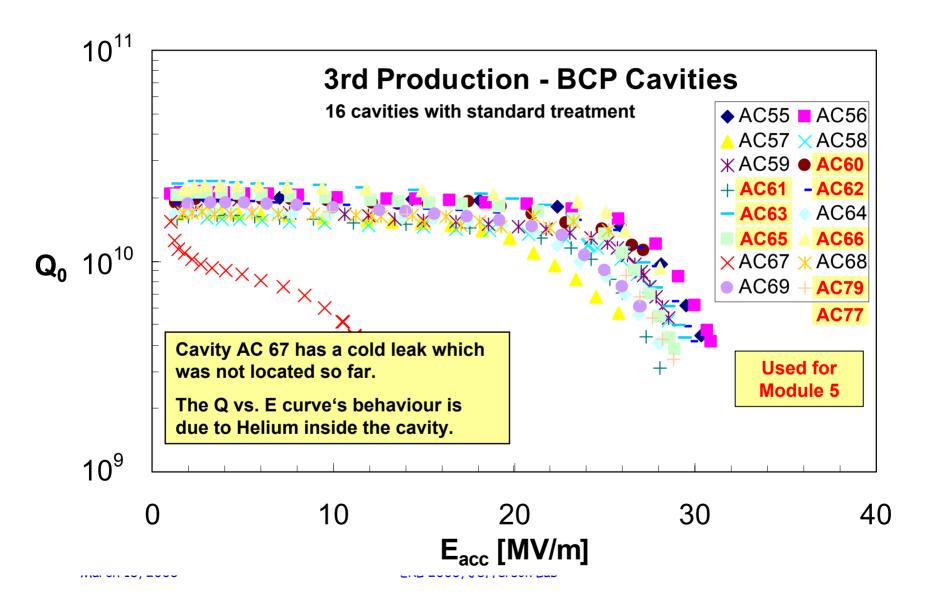
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Electropolishing

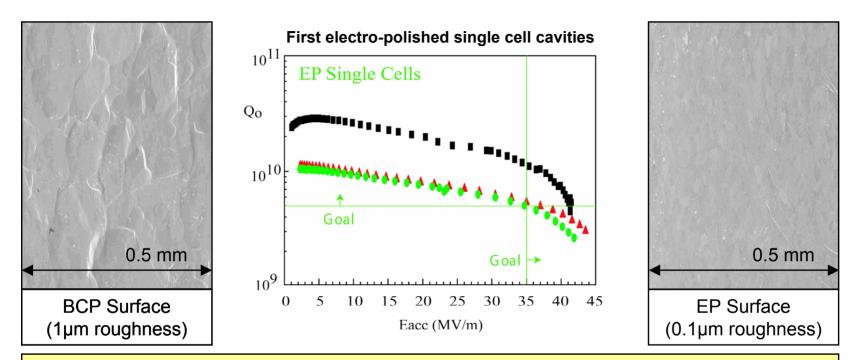
Absorption of Hydrogen avoided by applying a potential to the sample and adding an oxidizer (HNO_3) to the EP solution [S.Higuchi, K.Saito SRF2003]



High Gradient Performance



35 MV/m for 800 GeV c.m.



Electro-polishing (EP) instead of the standard chemical polishing (BCP) eliminates grain boundary steps. The development of this technique is strongly connected to work done by Kenji Saito (KEK).

Gradients of 40 MV/m at Q values above 10¹⁰ are now reliably achieved in single cells at KEK, DESY/CERN and TJNAF.

The highest gradient achieved was 42 MV/m.